

MCH6660



Power MOSFET

20V, 136mΩ, 2A, -20V, 266mΩ, -1.5A Complementary Dual

ON Semiconductor®

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Features

- ON-resistance Nch : $R_{DS(on)1}=105m\Omega$ (typ.)
Pch : $R_{DS(on)1}=205m\Omega$ (typ.)
- 1.8V Drive
- Pb-Free, Halogen Free and RoHS Compliance
- ESD Diode - Protected Gate
- Ultrasmall Package MCPH6(2.0mm×2.1mm×0.85mm)
- Nch MOSFET and Pch MOSFET are put in MCPH6 Package

Applications

- General-Purpose Switching Device Applications

Specifications

Absolute Maximum Ratings at $T_a=25^\circ C$

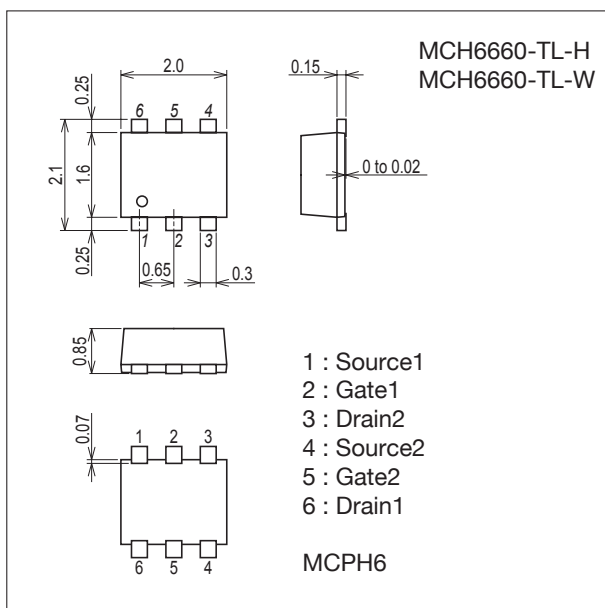
Parameter	Symbol	Conditions	N-channel	P-channel	Unit
Drain-to-Source Voltage	V_{DSS}		20	-20	V
Gate-to-Source Voltage	V_{GSS}		± 10	± 10	V
Drain Current (DC)	I_D		2	-1.5	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	8	-6	A
Power Dissipation	P_D	When mounted on ceramic substrate (900mm ² ×0.8mm) 1unit	0.8		W
Junction Temperature	T_j		150		°C
Storage Temperature	T_{stg}		-55 to +150		°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Package Dimensions

unit : mm (typ)

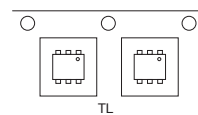
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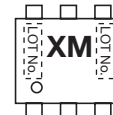
Product & Package Information

- Package : MCPH6
- JEITA, JEDEC : SC-88, SC-70-6, SOT-363
- Minimum Packing Quantity : 3,000 pcs./reel

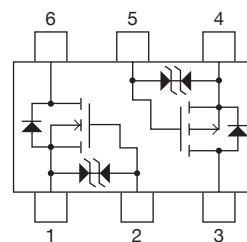
Packing Type : TL



Marking



Electrical Connection



ORDERING INFORMATION

See detailed ordering and shipping information on page 8 of this data sheet.

MCH6660

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
[N-channel]						
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	20			V
Zero-Gate Voltage Drain Current	IDSS	VDS=20V, VGS=0V			1	μA
Gate-to-Source Leakage Current	IGSS	VGS=±8V, VDS=0V			±10	μA
Gate Threshold Voltage	VGS(th)	VDS=10V, ID=1mA	0.4		1.3	V
Forward Transconductance	gFS	VDS=10V, ID=1A		1.9		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=1A, VGS=4.5V		105	136	mΩ
	RDS(on)2	ID=0.5A, VGS=2.5V		147	205	mΩ
	RDS(on)3	ID=0.3A, VGS=1.8V		212	318	mΩ
Input Capacitance	Ciss	VDS=10V, f=1MHz		128		pF
Output Capacitance	Coss			28		pF
Reverse Transfer Capacitance	Crss			21		pF
Turn-ON Delay Time	t _{d(on)}		See specified Test Circuit.		5.1	
Rise Time	t _r			11		ns
Turn-OFF Delay Time	t _{d(off)}			14.5		ns
Fall Time	t _f			12		ns
Total Gate Charge	Qg	VDS=10V, VGS=4.5V, ID=2A			1.8	
Gate-to-Source Charge	Qgs			0.3		nC
Gate-to-Drain "Miller" Charge	Qgd			0.55		nC
Forward Diode Voltage	VSD		IS=2A, VGS=0V		0.85	1.2
[P-channel]						
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-20			V
Zero-Gate Voltage Drain Current	IDSS	VDS=-20V, VGS=0V			-1	μA
Gate-to-Source Leakage Current	IGSS	VGS=±8V, VDS=0V			±10	μA
Gate Threshold Voltage	VGS(th)	VDS=-10V, ID=-1mA	-0.4		-1.4	V
Forward Transconductance	gFS	VDS=-10V, ID=-750mA		1.9		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=-750mA, VGS=-4.5V		205	266	mΩ
	RDS(on)2	ID=-300mA, VGS=-2.5V		295	413	mΩ
	RDS(on)3	ID=-100mA, VGS=-1.8V		430	645	mΩ
Input Capacitance	Ciss	VDS=-10V, f=1MHz		120		pF
Output Capacitance	Coss			26		pF
Reverse Transfer Capacitance	Crss			20		pF
Turn-ON Delay Time	t _{d(on)}		See specified Test Circuit.		5.3	
Rise Time	t _r			9.7		ns
Turn-OFF Delay Time	t _{d(off)}			16		ns
Fall Time	t _f			14		ns
Total Gate Charge	Qg	VDS=-10V, VGS=-4.5V, ID=-1.5A			1.7	
Gate-to-Source Charge	Qgs			0.28		nC
Gate-to-Drain "Miller" Charge	Qgd			0.47		nC
Forward Diode Voltage	VSD		IS=-1.5A, VGS=0V		-0.89	-1.2

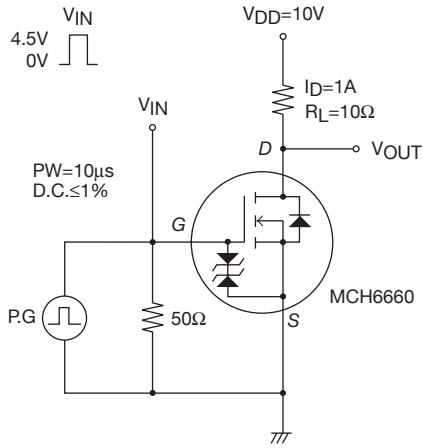
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Thermal Resistance Ratings

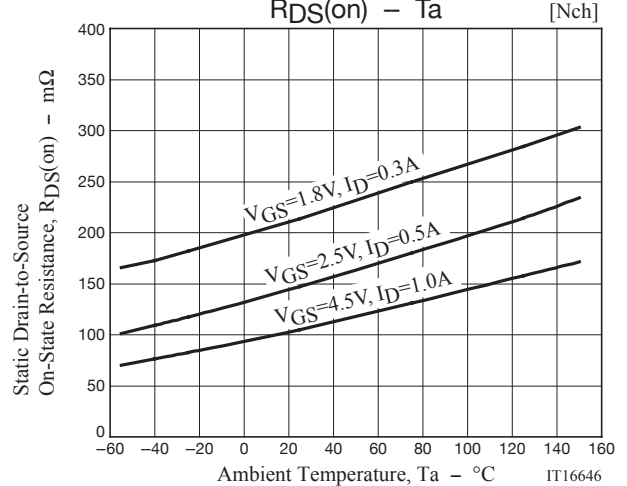
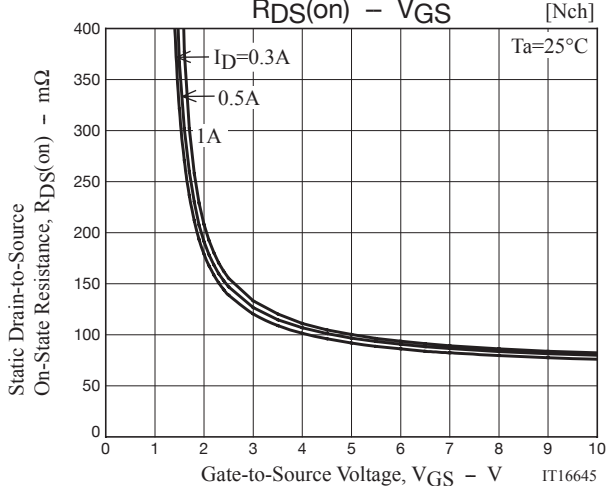
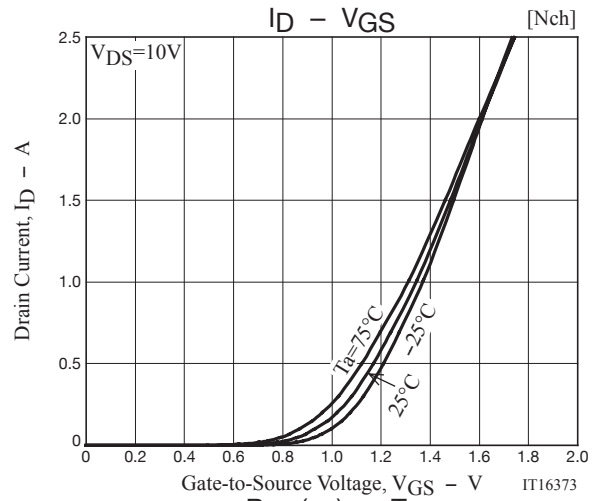
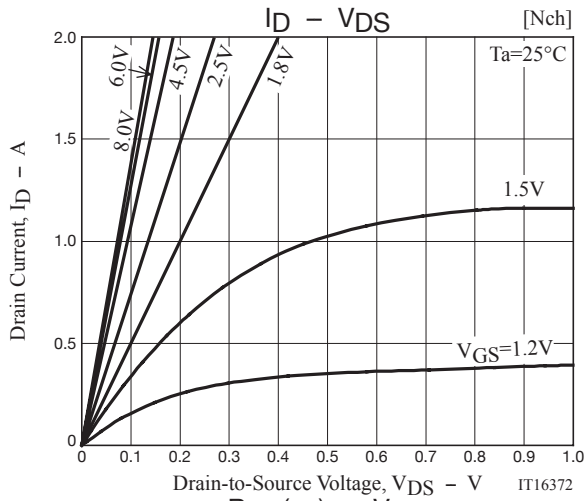
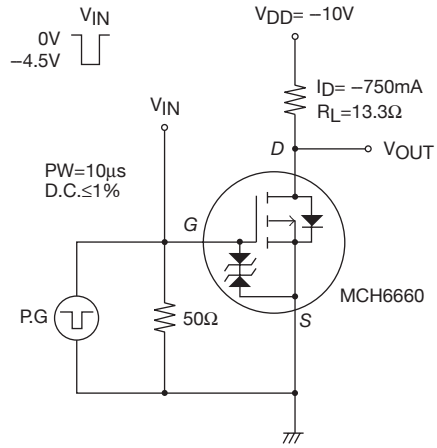
Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate (900mm ² ×0.8mm) 1unit	R _{θJA}	156.3	°C/W

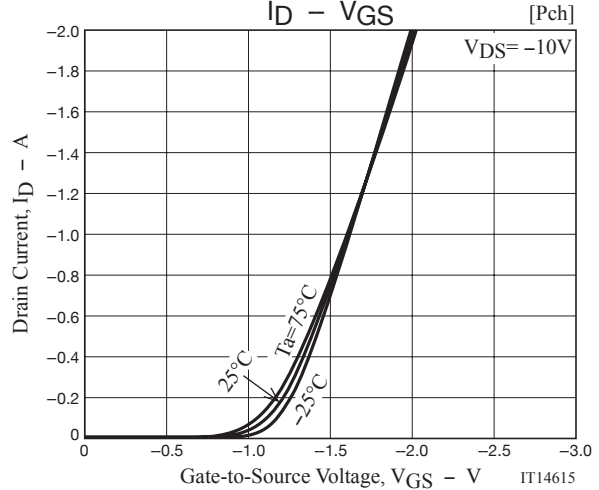
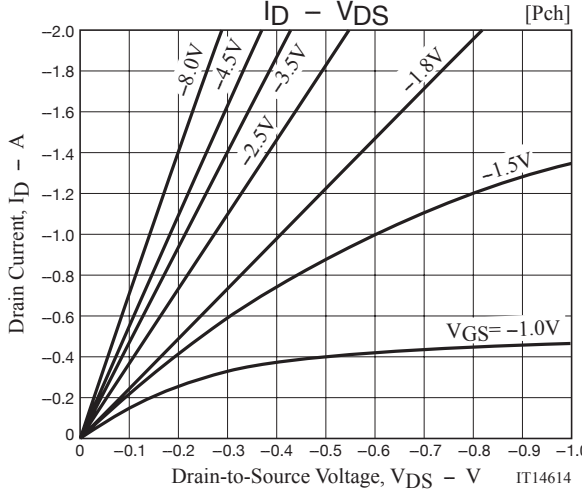
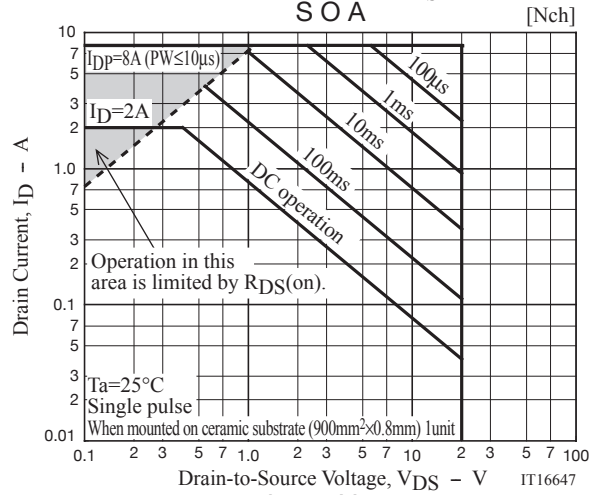
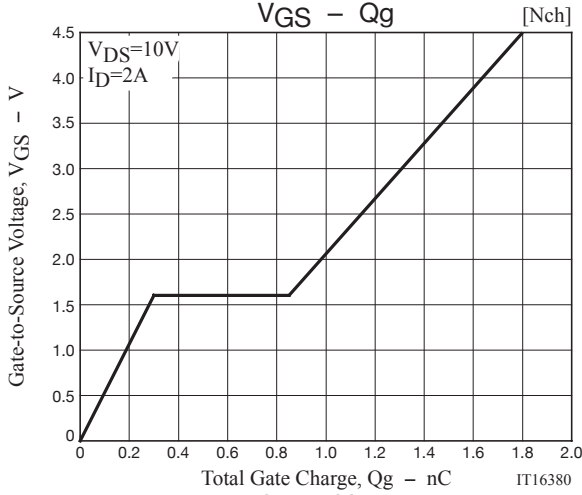
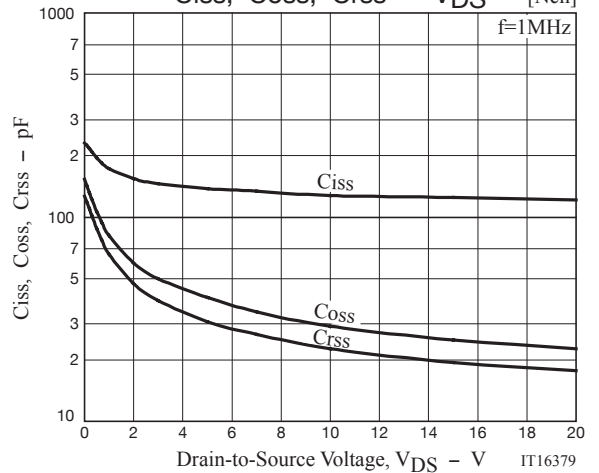
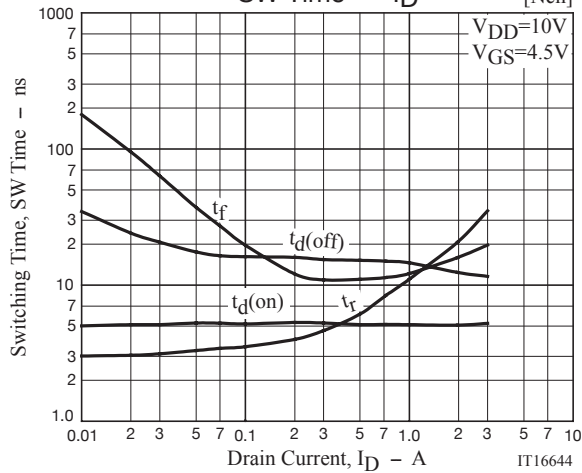
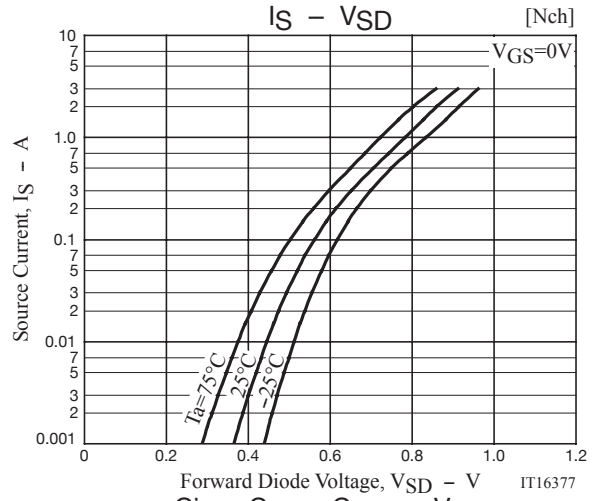
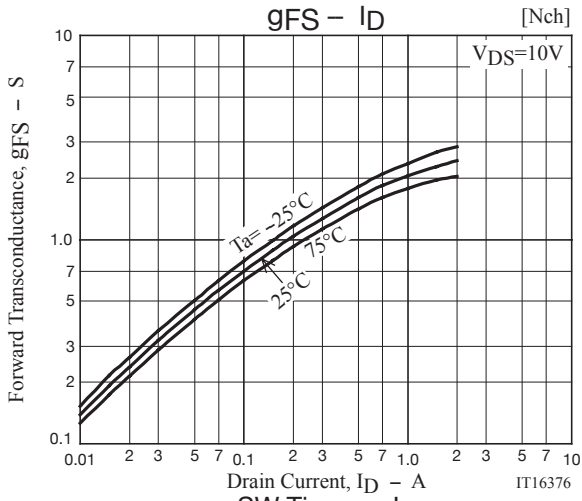
Switching Time Test Circuit

[N-channel]

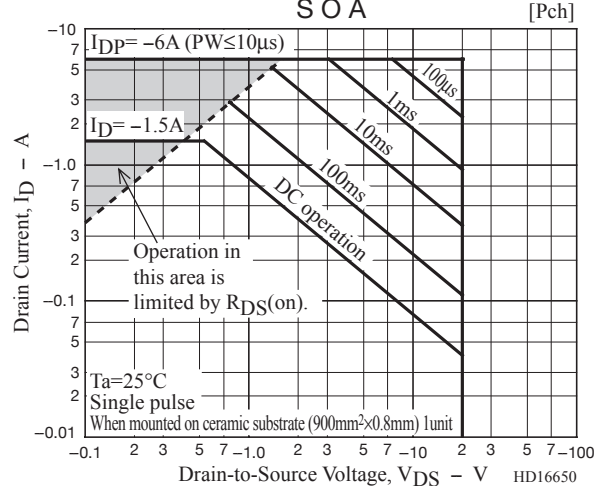
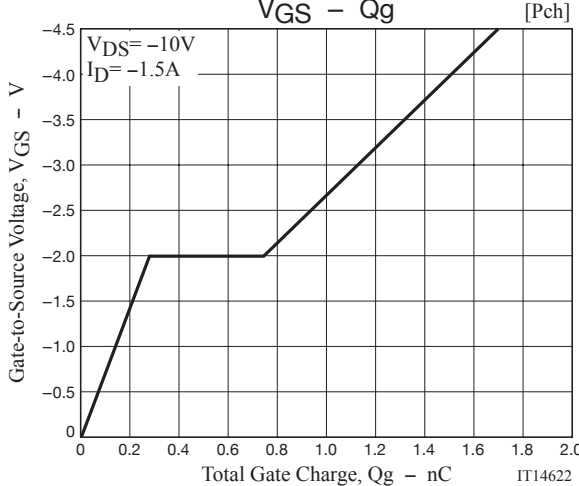
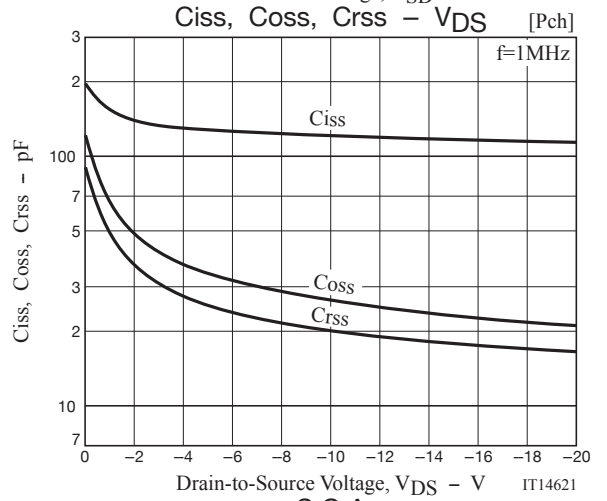
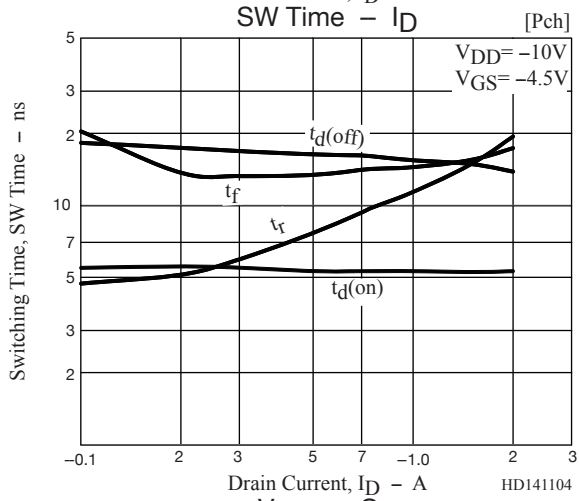
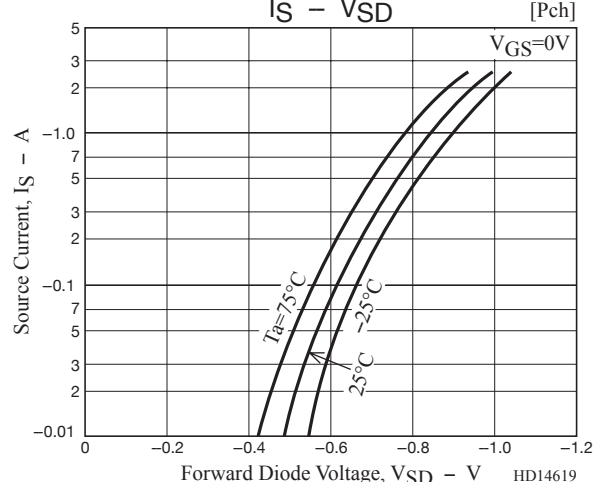
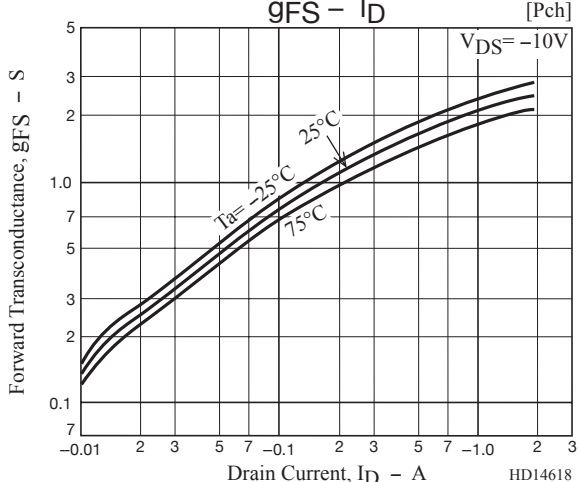
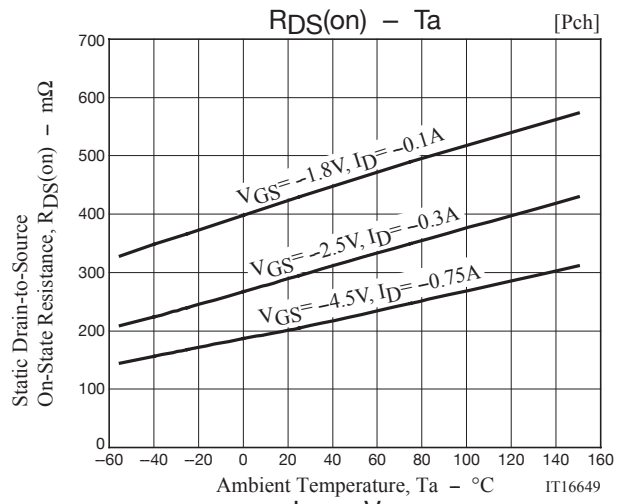
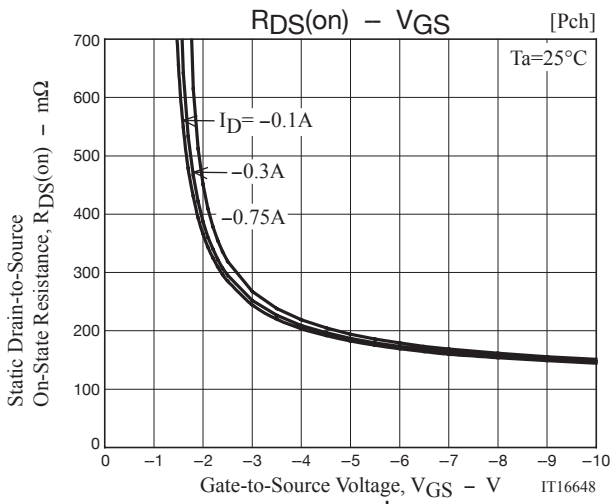


[P-channel]

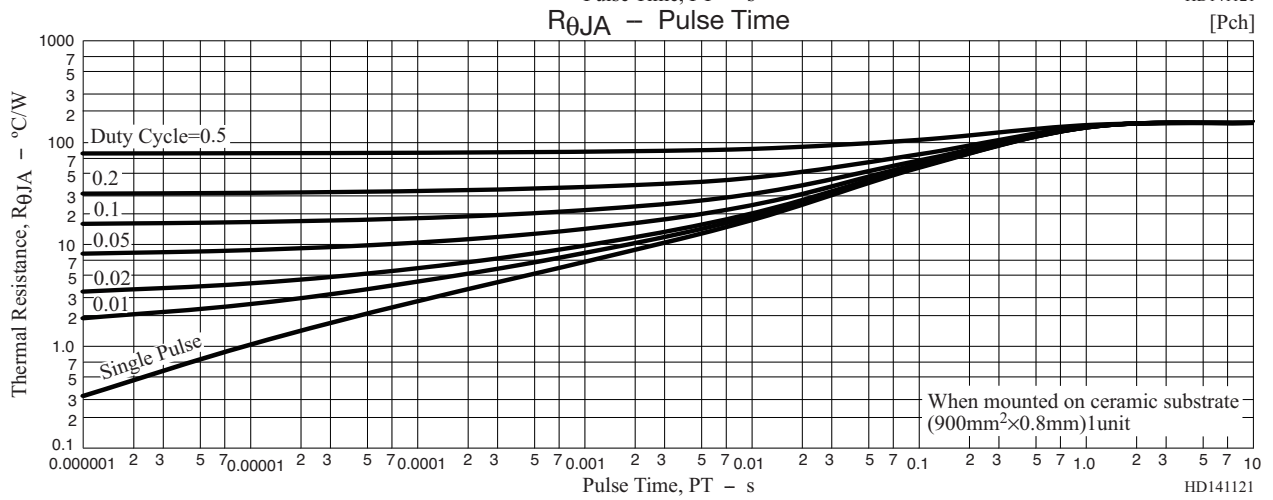
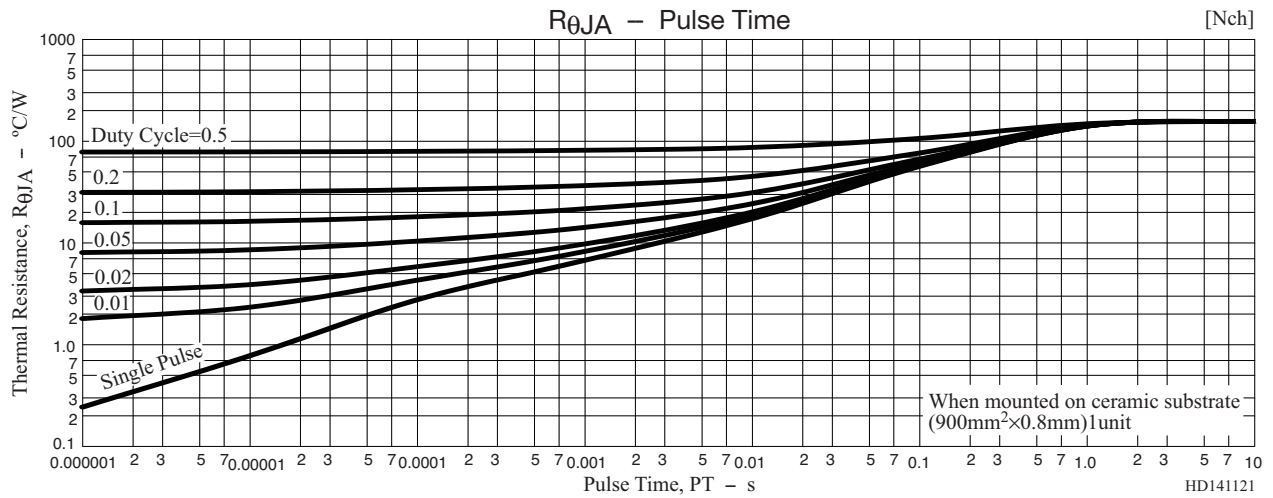
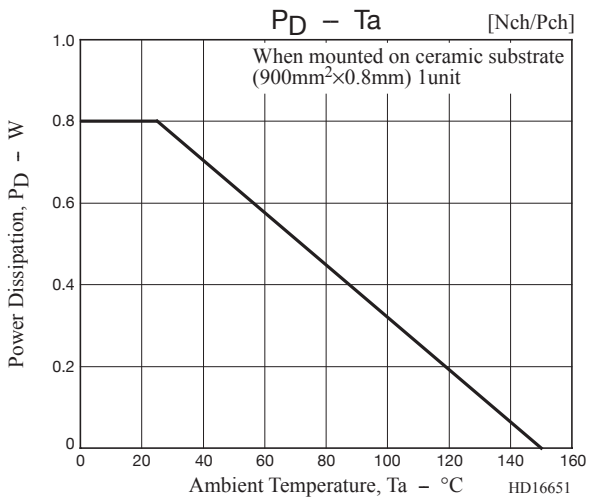




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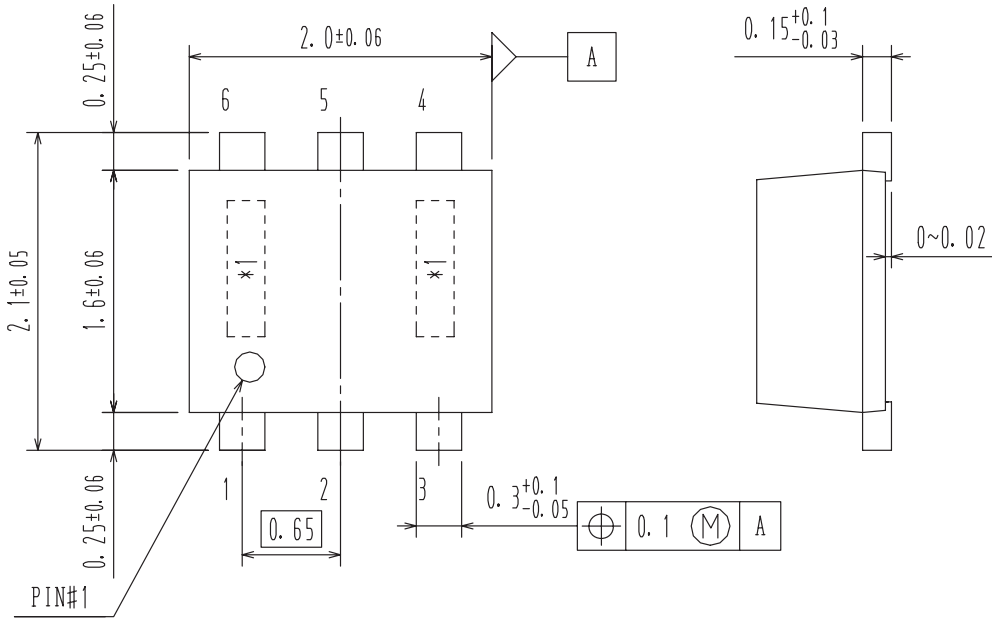
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Package Dimensions

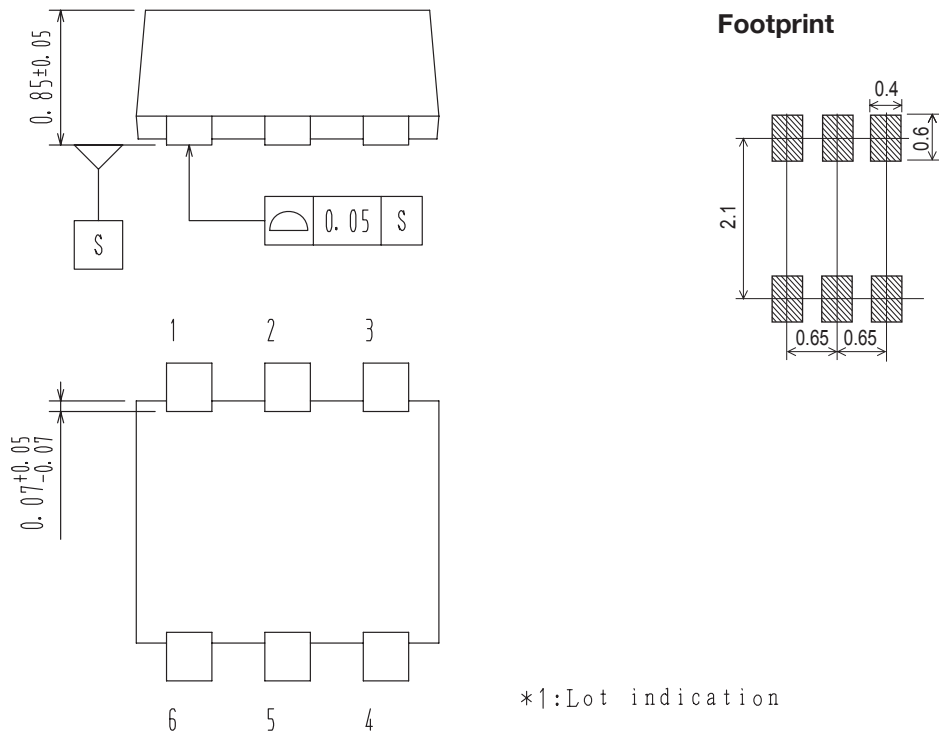
unit : mm

MCH6660-TL-H, MCH6660-TL-W

SC-88FL / MCPH6
CASE 419AS
ISSUE O



Recommended Soldering Footprint



*1: Lot indication

MCH6660

ORDERING INFORMATION

Device	Package	Shipping	memo
MCH6660-TL-H	MCPH6	3,000pcs./reel	Pb-Free and Halogen Free
MCH6660-TL-W			

Note on usage : Since the MCH6660 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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